LINEAR INTEGRATED CIRCUIT



The TDA 1170 is a monolithic integrated circuit in a 12-lead quad in-line plastic package. It is designed mainly for use in large and small screen black and white TV receivers.

The functions incorporated are:

- oscillator
- voltage ramp generator
- high power gain amplifier
- flyback generator

ABSOLUTE MAXIMUM RATINGS

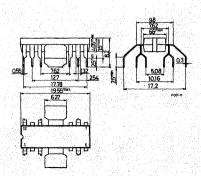
Vs	Supply voltage (pin 2)	27	v
V ₄ -V ₅	Flyback peak voltage	58	v
V ₈	Sync. input voltage	± 12	v
N.		∫ 10	v
V ₁₀	Power amplifier input voltage] -0.5	v
l _o	Output peak current (non-repetitive) @ $t = 2 ms$	2	А
l	Output peak current $(0, f) = 50 \text{ Hz}, t \le 10 \mu \text{s}$	2.5	А
'o	$@$ f = 50 Hz, t > 10 μ s	1.5	Α
P _{tot}	Power dissipation: at $T_{tab} = 90^{\circ}C$	5	w
	at T _{amb} = 80°C (free air)	1	w
T_{stg}, T_{j}	Storage and junction temperature	-40 to 150	°C

ORDERING NUMBER: TDA 1170

MECHANICAL DATA

Dimensions in mm

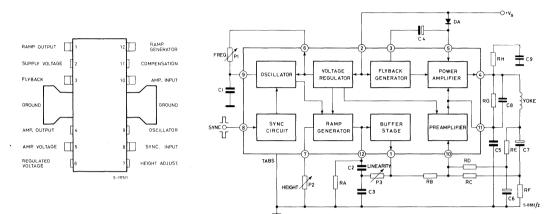
TDA1170



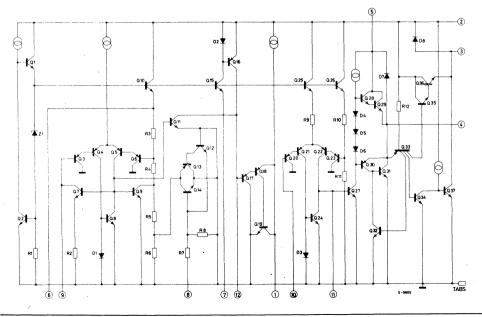


CONNECTION AND BLOCK DIAGRAM

(top view)



SCHEMATIC DIAGRAM



THERMAL DATA					
R _{th j-tab} Thermal resistance junction-tab		max	12	°C/W	
R _{th j-amb} Thermal resistance junction-ambient		max	70*	°C/W	

TDA1170

* Obtained with tabs soldered to printed circuit with minimized area.

ELECTRICAL CHARACTERISTICS (Refer to the test circuits, $V_s = 25V$, $T_{amb} = 25^{\circ}C$ unless otherwise specified)

	Parameter	Test conditions	Min.	Тур.	Max.	Unit	Fig.	
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DC CHARACTERISTICS

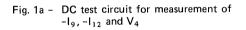
-1 ₉	Oscillator bias current	V ₉ = 1V			0.2	1	μA	- 1a
-I ₁₀	Amplifier input bias current	V ₁₀ = 1V			0.15	1	μΑ	1b
-I ₁₂	Ramp generator bias current				0.05	0.5	μΑ	1a
Vs	Supply voltage			10			v	-
V ₄	Quiescent output voltage		R1 = 30 kΩ R1 = 10 kΩ	8 4	8.8 4.4	9.6 4.8	v v	1a
V ₆ , V ₇	Regulated voltage			6	6.5	7	v	
$\frac{\Delta V_{6}}{\Delta V_{s}} \frac{\Delta V}{\Delta V}$	⁷ 7 s Line regulation	V _s = 10 to 2	7V		1.5		mV/V	1b

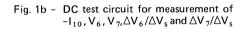
AC CHARACTERISTICS (f = 50 Hz)

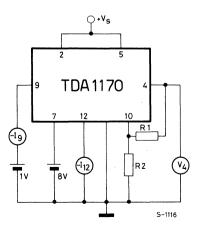
۱ _s	Supply current	ι. Ι _Υ = 1Α		140		mA	
١ _Y	Peak to peak yoke current (pin 4)				1.6	A	2
V ₄	Flyback voltage	I _Y = 1A		51		v	2
V ₈	Peak sync. input voltage (positive or negative)		1			v	

ELECTRICAL CHARACTERISTICS (continued)

	Parameter	Test conditions	Min.	Тур.	Max.	Unit	Fig
V9	Peak to peak oscillator sawtooth voltage			2.4		v	
R ₈	Sync. input resistance	V ₈ = 1V		3.5		kΩ	
t _{fly}	Flyback time	I _Y = 1A		0.6	0.8	ms	
δf	Pull-in range (below 50 Hz)			7		Hz	2
$\frac{\delta f}{\Delta V_s}$	Oscillator frequency drift with supply voltage	V _s = 10 to 27V		0.01		Hz V	
<u>δf</u> ∆T _{tab}	Oscillator frequency drift with tab temperature	T _{tab} = 40 to 120 °C		0.015		Hz °C	







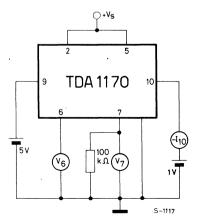
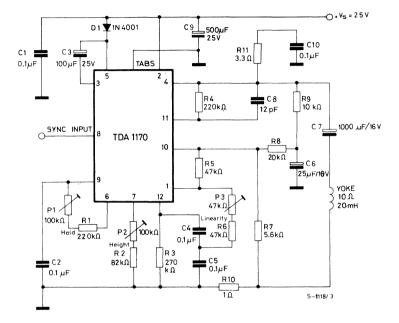
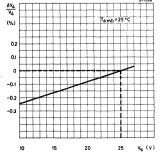


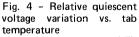


Fig. 2 - AC test circuit









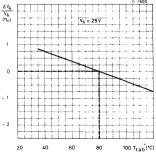
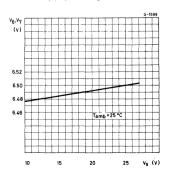
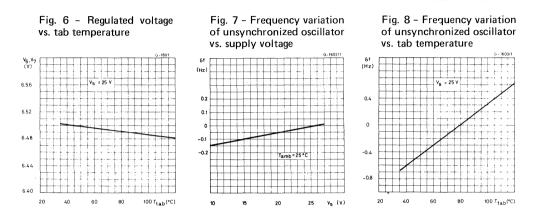


Fig. 5 - Regulated voltage vs. supply voltage







APPLICATION INFORMATION

The thermistor in series to the yokè is not required because the current feedback enables the yoke current to be independent of yoke resistance variations due to thermal effects. The oscillator is directly synchonized by the sync. pulses (positive or negative), therefore its free frequency must be lower than the sync. frequency. The flyback generator applies a voltage, about twice the supply voltage, to the yoke. This produces short flyback time together with a high useful power to dissipated power ratio.

The flyback time is:

$$t_{fiy} \cong \frac{2}{3} \frac{L_{Y} I_{Y}}{V_{s}}$$
 where: $L_{Y} = Yoke inductance$
 $V_{s} = Supply voltage$
 $I_{V} = Peak to peak voke current$

The supply current is:

$$I_{s} \cong \frac{I_{Y}}{8} + 0.02 \text{ (A)}$$

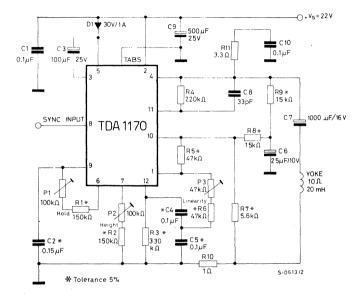
It does not depend on the value of V_s but only on yoke characteristics. The minimum value of V_s necessary for the required output current permits the maximum efficiency. The quiescent output voltage (pin 4) is fixed by the voltage feedback network R7, R8 and R9 (refer to fig. 2) according to:

$$V_4 = V_{10} - \frac{R7 + R8 + R9}{R7}$$

Pin 10 is the inverting input of the amplifier and its voltage is $V_{10} \cong 2V$.



Fig. 9 - Typical application circuit for B & W 24" 110° TV sets



Typical performance ($V_s = 22V$; $I_Y = 1A$; $R_Y = 10\Omega$; $L_Y = 20$ mH)

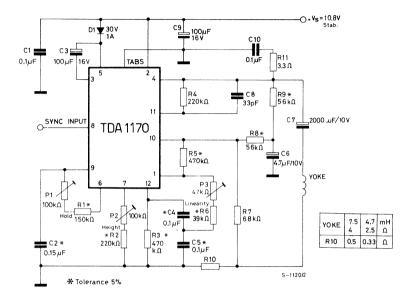
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١.	Supply current	140	mA
t _{flv}	Flyback time	0.75	ms
Iv.	Maximum scanning current (peak to peak)	1.2	А
V,	Operating supply voltage	20 to 24	v
P _{tot}	TDA 1170 power dissipation	2.2	w

For safe working up to $T_{amb} = 50^{\circ}$ C a heatsink of $R_{th} = 40^{\circ}$ C/W is required and each tab of TDA 1170 must be soldered to 1 cm² copper area of the printed circuit board.



Fig. 10 - Typical application circuit for B & W small screen TV sets



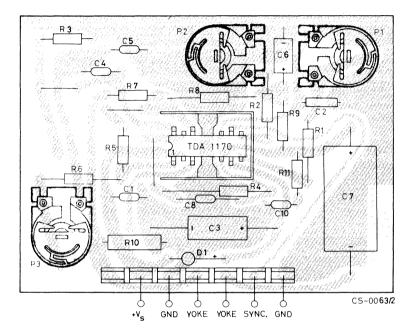
Typical performance (V_s = 10.8V; $I_Y = 1A$; $R_Y = 4\alpha$; $L_Y = 7.5$ mH)

١,	Supply current	150	mA
t _{flv}	Flyback time	0.7	ms
l _Y	Maximum scanning current (peak to peak)	1.15	А
V.	Operating supply voltage	10.8	V
P _{tot}	TDA 1170 power dissipation	1.3	W

For safe working up to $T_{amb} = 50^{\circ}C$ a heatsink of $R_{th} = 30^{\circ}C/W$ is required and each tab of the TDA 1170 must be soldereb to 1 cm² copper area of the printed circuit board.



Fig. 11 - P.C. board and component layout for the circuit of fig. 9 and fig. 10 (1:1 scale)



C9 is not mounted on the P.C. board.

MOUNTING INSTRUCTIONS

The junction to ambient thermal resistance of the TDA 1170 can be reduced by soldering the tabs to a suitable copper area of the printed circuit board (fig. 12) or to an external heatsink (fig. 13).

The diagram of fig. 16 shows the maximum dissipable power P_{tot} and the $R_{th \ j-amb}$ as a function of the side "s" of two equal square copper areas having a thickness of 35 μ (1.4 mil).

During soldering the tab temperature must not exceed 260 °C and the soldering time must not be longer than 12 seconds.

The external heatsink or printed circuit copper area must be connected to electrical ground.



Fig. 12 - Example of P.C. board copper area used as heatsink

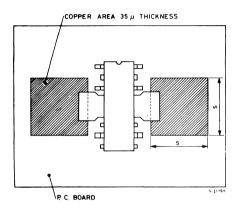


Fig. 13 - Example of TDA 1170 with external heatsink

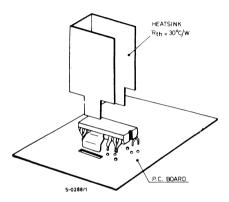


Fig. 14 – Maximum power dissipation and junction-ambient thermal resistance vs. "s"

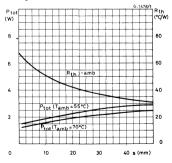


Fig. 15 - Maximum allowable power dissipation vs. ambient temperature

